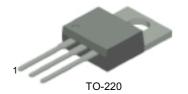


# KSE13006/13007

# High Voltage Switch Mode Application High Speed Switching

- Suitable for Switching Regulator and Motor Control



1.Base 2.Collector 3.Emitter

### **NPN Silicon Transistor**

### Absolute Maximum Ratings T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter	Value	Units	
V <sub>CBO</sub>	Collector-Base Voltage	: KSE13006	600	V
		: KSE13007	700	V
V <sub>CEO</sub>	Collector-Emitter Voltage	: KSE13006	300	V
		: KSE13007	400	V
V <sub>EBO</sub>	Emitter- Base Voltage		9	V
I <sub>C</sub>	Collector Current (DC)		8	Α
I <sub>CP</sub>	Collector Current (Pulse)		16	Α
I <sub>B</sub>	Base Current		4	Α
P <sub>C</sub>	Collector Dissipation (T <sub>C</sub> =25°C)		80	W
T <sub>J</sub>	Junction Temperature		150	°C
T <sub>STG</sub>	Storage Temperature		- 65 ~ 150	°C

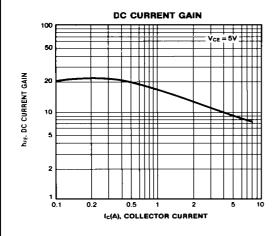
### Electrical Characteristics $\rm T_C = 25^{\circ}C$ unless otherwise noted

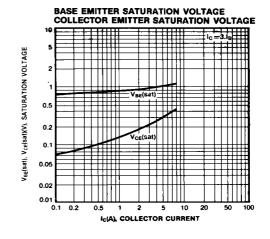
Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV <sub>CEO</sub>	Collector- Emitter Breakdown Voltage : KSE13006 : KSE13007	I <sub>C</sub> = 10mA, I <sub>B</sub> = 0	300 400			V V
I <sub>EBO</sub>	Emitter Cut-off Current	V <sub>EB</sub> = 9V, I <sub>C</sub> = 0			1	mA
h <sub>FE</sub>	*DC Current Gain	$V_{CE} = 5V, I_{C} = 2A$ $V_{CE} = 5V, I_{C} = 5A$	8 5		60 30	
V <sub>CE</sub> (sat)	*Collector-Emitter Saturation Voltage	$I_C = 2A, I_B = 0.4A$ $I_C = 5A, I_B = 1A$ $I_C = 8A, I_B = 2A$			1 2 3	V V V
V <sub>BE</sub> (sat)	*Base-Emitter Saturation Voltage	I <sub>C</sub> = 2A, I <sub>B</sub> = 0.4A I <sub>C</sub> = 5A, I <sub>B</sub> = 1A			1.2 1.6	V V
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> = 10V, f = 0.1MHz		110		pF
f <sub>T</sub>	Current Gain Bandwidth Product	V <sub>CE</sub> = 10V, I <sub>C</sub> = 0.5A	4			MHz
t <sub>ON</sub>	Turn ON Time	V <sub>CC</sub> = 125V, I <sub>C</sub> = 5A			1.6	μs
t <sub>S</sub>	Storage Time	$I_{B1} = -I_{B2} = 1A$			3	μs
t <sub>F</sub>	Fall Time	$R_L = 50\Omega$			0.7	μs

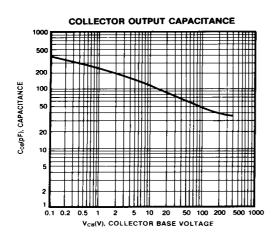
<sup>\*</sup> Pulse test: PW≤300µs, Duty cycle≤2%

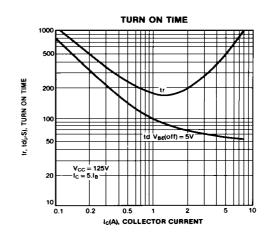
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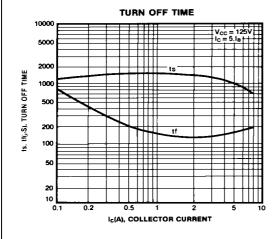
### **Typical Characteristics**

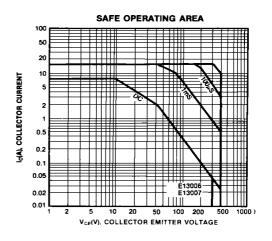






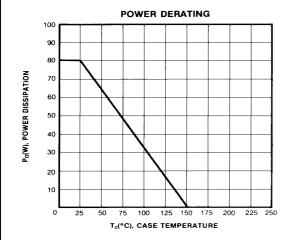






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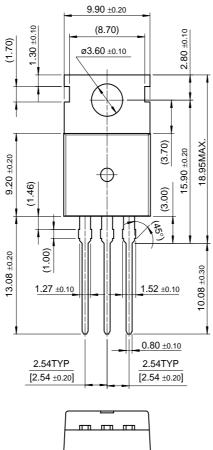
# Typical Characteristics (continued)

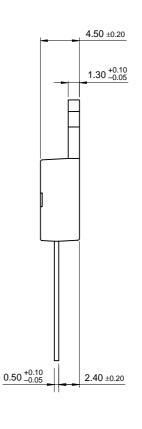


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# Package Dimensions

# TO-220





 $10.00 \pm 0.20$ 

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